	Type	Hits	Search Text	DBs	Time Stamp
1	BRS	15	((p$1sin) and ((257/$3.cor.) or (438/$3.cor.))) and hitachi.as.	USPAT; US-PGPUB	2004/05/22
2	BRS	0	(((third or "3rd") adj gate) with (potential))) and ((257/407,412.ccls.))	USPAT; US-PGPUB	2004/05/23
3	BRS	0	((((third or "3rd") adj gate) with (potential))) and ((257/407.ccls.))	USPAT; US-PGPUB	2004/05/23
4	BRS	0	((((third or "3rd") adj gate) with (potential))) and ((257/412.ccls.))	USPAT; US-PGPUB	2004/05/23
5	BRS	6	((third or "3rd") adj gate) and ((((257/412.cor.))) and (@ad<20030828 or @rlad<20030828))	USPAT; US-PGPUB	2004/05/23
6	BRS	2	(((third or "3rd") adj gate) and ((((257/407.cor.)))) and (@ad<20030828 or @rlad<20030828)	USPAT; US-PGPUB	2004/05/23
7	BRS	5	((third or "3rd") adj gate) and ((((257/407.ccls.))) and ((@ad<20030828 or @rlad<20030828))	USPAT; US-PGPUB	2004/05/23
8	BRS	18	((third or "3rd") adj gate) and ((((257/412.ccls.))) and ((@ad<20030828 or @rlad<20030828))	USPAT; US-PGPUB	2004/05/23
9	BRS	4	(US-6355531-$ or US-6465305-$ or US-6693333-$ or US-6492690-$).did.	USPAT	2004/05/23
10	BRS	1	(p$1type adj gate) and ((US-6355531-$ or US-6465305-$ or US-6693333-$ or US-6492690-$).did.)	USPAT; US-PGPUB	2004/05/23
11	BRS	2	(p$1type with gate) and ((US-6355531-$ or US-6465305-$ or US-6693333-$ or US-6492690-$).did.)	USPAT; US-PGPUB	2004/05/23
12	BRS	2	((third or "3rd") adj gate) and (((257/407.cor.)))	USPAT; US-PGPUB	2004/05/23
13	BRS	0	((third or "3rd") adj (gate or electrode)) and (((((n$1type adj (gate or electrode)) with (n$1type adj (substrate or well)))) an	USPAT; US-PGPUB	2004/05/23
14	BRS	2	((n$1type adj (gate or electrode)) with (n$1type adj (substrate or well))) and (@ad<20030828 or @rlad<20030828) and (	USPAT; US-PGPUB	2004/05/23
15	BRS	2	((n$1type adj (gate or electrode)) with (n$1type adj (substrate or well))) and (@ad<20030828 or @rlad<20030828) and (	USPAT; US-PGPUB	2004/05/23
16	BRS	0	((n$1type adj (gate or electrode)) with ("same" adj (conductivity or impurity) adj type)) and (@ad<20030828 or @rlad<20	USPAT; US-PGPUB	2004/05/23
17	BRS	26	((gate or electrode) with ("same" adj (conductivity or impurity) adj type) with (substrate or well)) and (@ad<20030828 or	USPAT; US-PGPUB	2004/05/23
18	BRS	9	((n$1type adj (gate or electrode)) with (n$1type adj (substrate or well))) and (@ad<20030828 or @rlad<20030828) and (	USPAT; US-PGPUB	2004/05/23
19	BRS	10	(((gate or electrode) with ("same" adj (conductivity or impurity) adj type) with (substrate or well)) and (@ad<20030828 or	USPAT; US-PGPUB	2004/05/23
20	BRS	16	((((n$1type adj (gate or electrode)) with (n$1type adj (substrate or well)))) and (@ad<20030828 or @rlad<20030828)) an	USPAT; US-PGPUB	2004/05/23
21	BRS	6	((gate or electrode) with ("same" adj (conductivity or impurity) adj type)) and ((@ad<20030828 or @rlad<20030828) an	USPAT; US-PGPUB	2004/05/23
22	BRS	3	((third or "3rd") adj (gate or electrode)) and ((@ad<20030828 or @rlad<20030828) and ((gate or electrode) with (work	USPAT; US-PGPUB	2004/05/23
23	BRS	0	(@ad<20030828 or @rlad<20030828) and ((work$1function or (work adj function) or fermi) with (higher or lower)) and (	USPAT; US-PGPUB	2004/05/23
24	BRS	1	(@ad<20030828 or @rlad<20030828) and ((work$1function or (work adj function) or fermi)) and (dram or (dynamic adj	USPAT; US-PGPUB	2004/05/23
25	BRS	10	(@ad<20030828 or @rlad<20030828) and (((third or "3rd") adj (gate or electrode) with (higher or lower) with (work$1fun	USPAT; US-PGPUB	2004/05/23
26	BRS	3	((third or "3rd") adj (gate or electrode) with (work$1function or (work adj function) or fermi)) and ((@ad<20030828 or @r	USPAT; US-PGPUB	2004/05/23
27	BRS	8	((third or "3rd") adj (gate or electrode) with (work$1function or (work adj function) or fermi or potential)) and ((@ad<2003	USPAT; US-PGPUB	2004/05/23
28	BRS	1	"6693333" and (polysilicon or poly$1si)	USPAT; US-PGPUB	2004/05/23
29	BRS	13	(	USPAT; US-PGPUB	2004/05/23
30	BRS	12	(gate with lowest with fermi) and ((@ad<20030828 or @rlad<20030828)	USPAT; US-PGPUB	2004/05/24
31	BRS	4	(((((gate or electrode) with (work$1function or (work adj function) or fermi or potential) with intermediate)) and (@ad<20	USPAT; US-PGPUB	2004/05/24
32	BRS	27	((((gate or electrode) with (work$1function or (work adj function) or fermi or potential) with intermediate)) and (@ad<200	USPAT; US-PGPUB	2004/05/24
33	BRS	0	((((gate or electrode) with (work$1function or (work adj function) or fermi) with intermediate)) and (@ad<20030828 or	USPAT; US-PGPUB	2004/05/24
34	BRS	0	((((gate or electrode) with (work$1function or (work adj function) or fermi) with intermediate)) and (@ad<20030828 or	USPAT; US-PGPUB	2004/05/24
35	BRS	32	((((gate or electrode) with (work$1function or (work adj function) or fermi) with intermediate)) and (@ad<20030828 or @	USPAT; US-PGPUB	2004/05/24
36	BRS	8	((((gate or electrode) with (work$1function or (work adj function) or fermi) with intermediate)) and (@ad<20030828 or	USPAT; US-PGPUB	2004/05/24
37	BRS	19	((third or "3rd") adj (work$1function or (work adj function) or fermi))	USPAT; US-PGPUB	2004/05/24
38	BRS	13	(((third or "3rd") adj (work$1function or (work adj function)))) and ((@ad<20030828 or @rlad<20030828) and ((	USPAT; US-PGPUB	2004/05/24
39	BRS	23	((third or "3rd") adj2 (work$1function or (work adj function) or fermi))	USPAT; US-PGPUB	2004/05/24
40	BRS	16	(((third or "3rd") adj2 (work$1function or (work adj function) or fermi))) and ((@ad<20030828 or @rlad<20030828) and (	USPAT; US-PGPUB	2004/05/24
41	BRS	3	((((third or "3rd") adj2 (work$1function or (work adj function) or fermi))) and ((@ad<20030828 or @rlad<20030828) and	USPAT; US-PGPUB	2004/05/24
42	BRS	5	((((third or "3rd") adj2 (work$1function or (work adj function) or fermi))) and ((@ad<20030828 or @rlad<20030828) an	USPAT; US-PGPUB	2004/05/24
43	BRS	34	((third or "3rd") near2 (work$1function or (work adj function) or fermi))	USPAT; US-PGPUB	2004/05/24
44	BRS	31	(((third or "3rd") near2 (work$1function or (work adj function) or fermi))) and ((@ad<20030828 or @rlad<20030828) and	USPAT; US-PGPUB	2004/05/24

	Type	Hits	Search Text	DBs	Time Stamp
44	BRS	21	(((third or "3rd") near2 (work$1function or (work adj function) or fermi))) and (@ad<20030828 or @rlad<20030828) and	USPAT; US-PGPUB	2004/05/24
45	BRS	20	((((third or "3rd") adj (gate or electrode)) with (work$1function or (work adj function) or fermi))) and (@ad<20030828 o	USPAT; US-PGPUB	2004/05/24
46	BRS	20	(((third or "3rd") adj (gate or electrode)) with (work$1function or (work adj function) or fermi))	USPAT; US-PGPUB	2004/05/24
47	BRS	13	("4399605"	USPAT; US-PGPUB	2004/05/24
48	BRS	1	(((third or "3rd") adj (gate or electrode))) and (("4399605"	USPAT; US-PGPUB	2004/05/24
49	BRS	0	(("4399605"	USPAT; US-PGPUB	2004/05/24
50	BRS	11	((gate or electrode) with (work$1function or (work adj function) or fermi or potential)) and ((	USPAT; US-PGPUB	2004/05/24
51	BRS	14	((((third or "3rd") adj (gate or electrode)) with (work$1function or (work adj function) or fermi))) and (@ad<20030828 o	USPAT; US-PGPUB	2004/05/24
52	BRS	11	(("4399605"	USPAT; US-PGPUB	2004/05/24
53	BRS	26	((doped adj both)) and (@ad<20030828 or @rlad<20030828) and ((257/$3.cor.) or (438/$3.cor.))) and ((gate or electro	USPAT; US-PGPUB	2004/05/27
54	BRS	14	((((third or "3rd") adj (gate or electrode)) with (work$1function or (work adj "function") or fermi))) and (@ad<20030828 or	USPAT; US-PGPUB	2004/05/27
55	BRS	1	(6693333.PN.) and (dopant or doping or dope or doped or impurity or boron or phosphorus)	USPAT; US-PGPUB	2004/05/27
56	BRS	20	((((third or "3rd") adj (gate or electrode)) with (work$1function or (work adj "function") or fermi))	USPAT; US-PGPUB	2004/05/27
57	BRS	1	((((third or "3rd") adj (work$1function or (work adj "function") or fermi) with (fet or (field adj effect) or mosfet or misfet or igf	USPAT; US-PGPUB	2004/05/27
58	BRS	1	((((third or "3rd") adj2 (work$1function or (work adj "function") or fermi)) with (fet or (field adj effect) or mosfet or misfet or ig	USPAT; US-PGPUB	2004/05/27
59	BRS	0	((((three) adj2 (work$1function or (work adj "function") or fermi)) with (fet or (field adj effect) or mosfet or misfet or igfet))	USPAT; US-PGPUB	2004/05/27
60	BRS	3	((((three) adj2 (work$1function or (work adj "function") or fermi)) with (gate or electrode))	USPAT; US-PGPUB	2004/05/27
61	BRS	0	("5436178"|"5093701"|"5801427").PN. and ("6265258"|"6376888").PN. and ("5436178"	USPAT; US-PGPUB	2004/05/27
62	BRS	5	("5436178" "5093701" "5801427" "6265258" "6376888" "5436178"	USPAT; US-PGPUB	2004/05/27
63	BRS	1	((((three) adj (gate or electrode)) with (work$1function or (work adj "function") or fermi))	USPAT; US-PGPUB	2004/05/27
64	BRS	2	(257/407.ccls.) and ((three) adj (gate or electrode))	USPAT; US-PGPUB	2004/05/27
65	BRS	1	((((three) adj (fet or (field adj effect) or mosfet or misfet or igfet)) with (work$1function or (work adj "function") or fermi)	USPAT; US-PGPUB	2004/05/27
66	BRS	2	(("5436178" "5093701" "5801427" "6265258" "6376888" "5436178"	USPAT; US-PGPUB	2004/05/27
67	BRS	1	((three) adj (fet or (field adj effect) or mosfet or misfet or igfet)) and ((257/407.ccls.) or (257/412.ccls.))	USPAT; US-PGPUB	2004/05/27
68	BRS	26	"4786611"	USPAT; US-PGPUB	2004/05/27
69	BRS	10	"4786611" and (work$1function or (work adj "function") or fermi)	USPAT; US-PGPUB	2004/05/27
70	BRS	1	((((third or "3rd") adj (fet or (field adj effect) or mosfet or misfet or igfet)) with (work$1function or (work adj "function") or fer	USPAT; US-PGPUB	2004/05/27
71	BRS	3	(257/412.ccls.) and ((three) adj (gate or electrode))	USPAT; US-PGPUB	2004/05/27
72	BRS	2	((three) adj (fet or (field adj effect) or mosfet or misfet or igfet)) and (438/585,587,588,592.ccls.)	USPAT; US-PGPUB	2004/05/27
73	BRS	26	"4786611" and (@ad<20030828 or @rlad<20030828)	USPAT; US-PGPUB	2004/05/27
74	BRS	3	"5907777" and (@ad<20030828 or @rlad<20030828)	USPAT; US-PGPUB	2004/05/27
75	BRS	8	((((p$1type or (p adj type) adj (gate or electrode) near (n$1channel or (n adj channel) or nmos))	USPAT; US-PGPUB	2004/05/27
76	BRS	8	(((((p$1type or (p adj type)) adj (gate or electrode)) near (n$1channel or (n adj channel) or nmos))) and (@ad<20030828 o	USPAT; US-PGPUB	2004/05/27
77	BRS	0	"4786611" with (work$1function or (work adj "function") or fermi)	USPAT; US-PGPUB	2004/05/27
78	BRS	2	(gate with (work$1function or (work adj "function") or fermi) with doping with amount)	USPAT; US-PGPUB	2004/05/27
79	BRS	30	(((((p$1type or (p adj type)) adj (gate or electrode)) near2 (n$1channel or (n adj channel) or nmos))) and (@ad<20030828	USPAT; US-PGPUB	2004/05/27
80	BRS	0	("4786611" and (@ad<20030828 or @rlad<20030828)) and ((three) adj (gate or electrode))	USPAT; US-PGPUB	2004/05/27
81	BRS	0	(((((n$1type or (n adj type)) adj (gate or electrode)) near2 (n$1channel or (n adj channel) or nmos))) and (@ad<20030828	USPAT; US-PGPUB	2004/05/27
82	BRS	3	(((((n$1type or (n adj type)) adj (gate or electrode)) near2 (n$1channel or (n adj channel) or nmos))) and (@ad<20030828	USPAT; US-PGPUB	2004/05/27
83	BRS	2	("4786611" and (@ad<20030828 or @rlad<20030828)) and ((three) adj (fet or (field adj effect) or mosfet or misfet or igfet)	USPAT; US-PGPUB	2004/05/27
84	BRS	0	(((((n$1type or (n adj type)) adj (gate or electrode)) near2 (n$1channel or (n adj channel) or nmos))) and (@ad<20030828	USPAT; US-PGPUB	2004/05/27
85	BRS	30	(((((p$1type or (p adj type)) adj (gate or electrode)) near2 (n$1channel or (n adj channel) or nmos))	USPAT; US-PGPUB	2004/05/27
86	BRS	16	(((((n$1type or (n adj type)) adj (gate or electrode)) near2 (n$1channel or (n adj channel) or nmos)) and (((((p$1type or (p a	USPAT; US-PGPUB	2004/05/27
87	BRS	0	(((((n$1type or (n adj type)) adj (gate or electrode)) near2 (n$1channel or (n adj channel) or nmos))) and (@ad<20030828	USPAT; US-PGPUB	2004/05/27

	Type	Hits	Search Text	DBs	Time Stamp
87	BRS	0	(((((n$1type or (n adj type)) adj (gate or electrode)) near2 (n$1channel or (n adj channel) or nmos))) and (@ad<20030828	USPAT; US-PGPUB	2004/05/27
88	BRS	3	(((((n$1type or (n adj type)) adj (gate or electrode)) near2 (n$1channel or (n adj channel) or nmos))) and (@ad<20030828	USPAT; US-PGPUB	2004/05/27
89	BRS	3	(((((n$1type or (n adj type)) adj (gate or electrode)) near2 (n$1channel or (n adj channel) or nmos))) and (((third or "3rd" or	USPAT; US-PGPUB	2004/05/27
90	BRS	5	(((((p$1type or (p adj type)) adj (gate or electrode)) near2 (n$1channel or (n adj channel) or nmos))) and (@ad<20030828)	USPAT; US-PGPUB	2004/05/27
91	BRS	16	(((((n$1type or (n adj type)) adj (gate or electrode)) near2 (n$1channel or (n adj channel) or nmos))) and ((((p$1type or (p	USPAT; US-PGPUB	2004/05/27
92	BRS	2	((((((n$1type or (n adj type)) adj (gate or electrode)) near2 (n$1channel or (n adj channel) or nmos))) and ((((p$1type or (p	USPAT; US-PGPUB	2004/05/27
93	BRS	35	(((((gate or electrode) with (work$1function or (work adj "function") or fermi))) and (dram or (dynamic adj (ram or random))	USPAT; US-PGPUB	2004/05/27
94	BRS	22	((((third or "3rd" or three) adj (gate or electrode or fet or (field adj effect) or mosfet or misfet or igfet)) with (work$1function	USPAT; US-PGPUB	2004/05/27
95	BRS	6	((((third or "3rd" or three) adj (gate or electrode or fet or (field adj effect) or mosfet or misfet or igfet)) with (work$1functio	USPAT; US-PGPUB	2004/05/29
96	BRS	22	((((third or "3rd" or three) adj (gate or electrode or fet or (field adj effect) or mosfet or misfet or igfet)) with (work$1functio	USPAT; US-PGPUB	2004/05/29
97	BRS	3	((((cmos with (work$1function or (work adj "function") or fermi)) and (@ad<20030828 or @rlad<20030828)) and (dram or	USPAT; US-PGPUB	2004/05/29
98	BRS	35	((gate or electrode) with (work$1function or (work adj "function") or fermi)) and ((@ad<20030828 or @rlad<20030828) an	USPAT; US-PGPUB	2004/05/29
99	BRS	0	(((gate or electrode) near "both" NEAR DOPED) with (pmos or p$1channel or (p adj channel))) and (@ad<20030828 or	USPAT; US-PGPUB	2004/05/29
100	BRS	0	(((gate or electrode) near "both") with boron with phosphorus with (pmos or p$1channel or (p adj channel))) and (@ad<2	USPAT; US-PGPUB	2004/05/29
101	BRS	0	((gate or electrode) with boron with phosphorus with (pmos or p$1channel or (p adj channel)) not (nmos or n$1channel or (	USPAT; US-PGPUB	2004/05/29
102	BRS	2	((gate or electrode) with ("both" adj boron adj phosphorus)) and (@ad<20030828 or @rlad<20030828)	USPAT; US-PGPUB	2004/05/29
103	BRS	7	((gate or electrode) near ("both" adj conductivity)) and (@ad<20030828 or @rlad<20030828)	USPAT; US-PGPUB	2004/05/29
104	BRS	35	((gate or electrode) with (work$1function or (work adj "function") or fermi)) and ((@ad<20030828 or @rlad<20030828) an	USPAT; US-PGPUB	2004/05/29
105	BRS	0	((gate or electrode) with ("both" adj boron adj phosphorus) with (pmos or p$1channel or (p adj channel))) and (@ad<200	USPAT; US-PGPUB	2004/05/29
106	BRS	0	(((gate or electrode) near2 ("both" adj (impurity or conductivity))) with (pmos or p$1channel or (p adj channel))) and (@a	USPAT; US-PGPUB	2004/05/29
107	BRS	0	(((gate or electrode) with("both" adj (impurity or conductivity))) with (pmos or p$1channel or (p adj channel))) and (@ad<	USPAT; US-PGPUB	2004/05/29
108	BRS	7	((gate or electrode) near ("both" adj (impurity or conductivity))) and (@ad<20030828 or @rlad<20030828)	USPAT; US-PGPUB	2004/05/29
109	BRS	0	(((gate or electrode) near ("both" adj (impurity or conductivity))) with (pmos or p$1channel or (p adj channel))) and ((@ad	USPAT; US-PGPUB	2004/05/29
110	BRS	7	(	USPAT; US-PGPUB	2004/05/29
111	BRS	9	"6043537"	USPAT; US-PGPUB	2004/05/29
112	BRS	4	(("6043537") and (@ad<20030828 or @rlad<20030828)) and (samsung.as.)	USPAT; US-PGPUB	2004/05/29
113	BRS	9	("6043537") and (@ad<20030828 or @rlad<20030828)	USPAT; US-PGPUB	2004/05/29
114	BRS	10	"6730952"	USPAT; US-PGPUB	2004/05/29
115	BRS	10	("6730952"	USPAT; US-PGPUB	2004/05/29
116	BRS	1	(("6730952"	USPAT; US-PGPUB	2004/05/29
117	BRS	1	(((dram or (dynamic adj (ram or random))).ab.) and (@ad<20030828 or @rlad<20030828) and ((257/$3.cor.) or (438/$3.	USPAT; US-PGPUB	2004/06/06
118	BRS	9	(((dram or (dynamic adj (ram or random))).ab.) and (@ad<20030828 or @rlad<20030828) and ((257/$3.cor.) or (438/$3.	USPAT; US-PGPUB	2004/06/06
119	BRS	0	(((dram or (dynamic adj (ram or random))).ab.) and (@ad<20030828 or @rlad<20030828) and ((257/$3.cor.) or (438/$3.	USPAT; US-PGPUB	2004/06/06
120	BRS	3	(((dram or (dynamic adj (ram or random))).ab.) and (@ad<20030828 or @rlad<20030828) and ((257/$3.cor.) or (438/$3.	USPAT; US-PGPUB	2004/06/06
121	BRS	4	((gate or electrode) with ((middle or intermediate or intermediary) adj (work$1function or (work adj "function") or fermi))	USPAT; US-PGPUB	2004/06/06
122	BRS	4	(((dram or (dynamic adj (ram or random))).ab.) and (@ad<20030828 or @rlad<20030828) and ((257/$3.cor.) or (438/$3.	USPAT; US-PGPUB	2004/06/06
123	BRS	1	((gate or electrode) with ((middle or intermediate or intermediary) adj (work$1function or (work adj "function") or fermi))	USPAT; US-PGPUB	2004/06/06
124	BRS	2	((gate or electrode) with ((middle or intermediate or intermediary) adj (work$1function or (work adj "function") or fermi or p	USPAT; US-PGPUB	2004/06/06
125	BRS	0	((gate or electrode) with ((multiple) adj (work$1function or (work adj "function") or fermi or potential)) and (((dram or (dyn	USPAT; US-PGPUB	2004/06/06
126	BRS	14	((gate or electrode) with ((three) adj (work$1function or (work adj "function") or fermi or potential)) and (((dram or (dyna	USPAT; US-PGPUB	2004/06/06
127	BRS	1	((gate or electrode) with ((different) adj (work$1function or (work adj "function") or fermi or bandgap or band$1gap))) and	USPAT; US-PGPUB	2004/06/06
128	BRS	2	((gate or electrode) with ((third) adj (work$1function or (work adj "function") or fermi or potential)) and (((dram or (dynam	USPAT; US-PGPUB	2004/06/06
129	BRS	11	((gate or electrode) with ((third) adj (work$1function or (work adj "function") or fermi)))	USPAT; US-PGPUB	2004/06/06
130	BRS	11	((gate or electrode) with ((third) adj (work$1function or (work adj "function") or fermi))) and (@ad<20030828 or @rlad	USPAT; US-PGPUB	2004/06/06

	Type	Hits	Search Text	DBs	Time Stan
130	BRS	11	((((gate or electrode) with ((third) adj (work$1function or (work adj "function") or fermi)))) and ((@ad<20030828 or @rlad	USPAT; US-PGPUB	2004/06/06
131	BRS	1	((poly$1si or (poly adj (si or silicon)) or poly$silicon) with ((third) adj (work$1function or (work adj "function") or fermi)))	USPAT; US-PGPUB	2004/06/06
132	BRS	0	(boron with phosphorus with ((third) adj (work$1function or (work adj "function") or fermi)))	USPAT; US-PGPUB	2004/06/06
133	BRS	0	(boron with phosphorus with ((third) adj (work$1function or (work adj "function") or bandgap or fermi)))	USPAT; US-PGPUB	2004/06/06
134	BRS	16	((gate or electrode) with ((third) adj (work$1function or (work adj "function") or fermi or bandgap)))	USPAT; US-PGPUB	2004/06/06
135	BRS	0	((triple) adj (work$1function or (work adj "function") or fermi or bandgap))	USPAT; US-PGPUB	2004/06/06
136	BRS	15	((((gate or electrode) with ((third) adj (work$1function or (work adj "function") or fermi or bandgap)))) and ((@ad<2003082	USPAT; US-PGPUB	2004/06/06
137	BRS	0	((gate or electrode) with ((triple) adj (work$1function or (work adj "function") or fermi or bandgap)))	USPAT; US-PGPUB	2004/06/06
138	BRS	3	((gate or electrode) with ("both" adj ((boron adj phosphorus) or (phosphorus adj boron))))	USPAT; US-PGPUB	2004/06/06
139	BRS	1	((gate or electrode) with ("both" adj ((boron adj phosphorus) or (phosphorus adj boron))))	EPO; JPO; DERWE	2004/06/06
140	BRS	32	((gate or electrode) with ("both" adj ((n$1type adj p$1type) or (p$1type adj n$1type))))	EPO; JPO; DERWE	2004/06/06
141	BRS	1	((gate or electrode) with ("both" adj ((n$1type adj p$1type) or (p$1type adj n$1type))) not "can")	USPAT; US-PGPUB	2004/06/06
142	BRS	24	(((gate or electrode) with "n+p")) and (@ad<20030828 or @rlad<20030828) and ((257/$3.cor.) or (438/$3.cor.))	USPAT; US-PGPUB	2004/06/06
143	BRS	9	((gate or electrode) with ((n$1type adj p$1type) or (p$1type adj n$1type))) with (work$1function or (work adj "f	USPAT; US-PGPUB	2004/06/06
144	BRS	8	(((gate or electrode) with ("both" adj ((n$1type adj p$1type) or (p$1type adj n$1type))) with (work$1function or (work adj "	USPAT; US-PGPUB	2004/06/06
145	BRS	6	((((gate or electrode) near (mid$1gap or (mid adj gap) or intrinsic))) and (@ad<20030828 or @rlad<20030828) and ((25	USPAT; US-PGPUB	2004/06/06
146	BRS	20	((cell or memory) with ((gate or electrode) near (mid$1gap or (mid adj gap) or intrinsic)))	USPAT; US-PGPUB	2004/06/06
147	BRS	3	((cell or memory) with ((gate or electrode) near (mid$1gap or (mid adj gap) or intrinsic))) and (@ad<20030828 or @rla	USPAT; US-PGPUB	2004/06/06
148	BRS	23	((peripheral or logic or support or cmos) with ((gate or electrode) near (mid$1gap or (mid adj gap) or intrinsic)))	USPAT; US-PGPUB	2004/06/06
149	BRS	18	((((peripheral or logic or support or cmos) with ((gate or electrode) near (mid$1gap or (mid adj gap) or intrinsic))) and (	USPAT; US-PGPUB	2004/06/06
150	BRS	1	"5079180".PN.	USPAT		2004/06/06
151	BRS	1	"5164805".PN.	USPAT		2004/06/06
152	BRS	1	"6424016".PN.	USPAT		2004/06/06
153	BRS	29	(((((poly$1si or (poly adj (si or silicon)) or poly$silicon) with ((gate or electrode) near (mid$1gap or (mid adj gap) or intrinsic	USPAT; US-PGPUB	2004/06/06
154	BRS	33	((((poly$1si or (poly adj (si or silicon)) or poly$silicon) with ((gate or electrode) near (mid$1gap or (mid adj gap) or intrinsic	USPAT; US-PGPUB	2004/06/06
155	BRS	7	("3673471"	USPAT; US-PGPUB	2004/06/06
156	BRS	4	"6424016"	USPAT; US-PGPUB	2004/06/06
157	BRS	23	((peripheral or logic or support or cmos) with ((gate or electrode) near (mid$1gap or (mid adj gap) or intrinsic or (middle a	USPAT; US-PGPUB	2004/06/06
158	BRS	3	("6424016") and (@ad<20030828 or @rlad<20030828) and ((257/$3.cor.) or (438/$3.cor.))	USPAT; US-PGPUB	2004/06/06
159	BRS	9	((pmos or (p adj channel) or p$1channel) near (mid$1gap or (mid adj gap) or intrinsic or (middle	USPAT; US-PGPUB	2004/06/06
160	BRS	7	(((pmos or (p adj channel) or p$1channel) with ((gate or electrode) near (mid$1gap or (mid adj gap) or intrinsic or (middle	USPAT; US-PGPUB	2004/06/06
161	BRS	5	(((((pmos or (p adj channel) or p$1channel) with ((gate or electrode) with (mid$1gap or (mid adj gap) or intrinsic or (middle	USPAT; US-PGPUB	2004/06/06
162	BRS	113	((pmos or (p adj channel) or p$1channel) with ((gate or electrode) with (mid$1gap or (mid adj gap) or intrinsic or (middle	USPAT; US-PGPUB	2004/06/06
163	BRS	3	((((((pmos or (p adj channel) or p$1channel) with (periphery or peripheral))) and ((nmos or (n adj channel) or n$1channe	USPAT; US-PGPUB	2004/06/06
164	BRS	9	("5369295"|"5397909"|"6607979"|"4686000"|"5814875"|"5654573"|"6479330"|"6586803"|"20030071310").PN.	USPAT; US-PGPUB	2004/06/06
165	BRS	11	("6380598"|"6607979"|"4686000"|"5164806"|"5814875"|"5654573"|"6479330"|"6586803"|"20030071310"|"5672526"|"58937	USPAT; US-PGPUB	2004/06/06
166	BRS	4	(("6380598"|"6607979"|"4686000"|"5164806"|"5814875"|"5654573"|"6479330"|"6586803"|"20030071310"|"5672526"|"5893	USPAT; US-PGPUB	2004/06/06
167	BRS	2	"6552401"	USPAT; US-PGPUB	2004/06/06
168	BRS	6	((n$doped adj (poly or poly$1si or polysilicon)) with gate with pmos)	USPAT; US-PGPUB	2004/06/06
169	BRS	4	(	USPAT; US-PGPUB	2004/06/06
170	BRS	2	"6448121"	USPAT; US-PGPUB	2004/06/06
171	BRS	113	((pmos or (p adj channel) or p$1channel) with (mid$1gap or (mid adj gap) or intrinsic or (middle adj band$1gap)) with (q	USPAT; US-PGPUB	2004/06/06
172	BRS	9	((pmos or (p adj channel) or p$1channel) with ((mid$1gap or (mid adj gap) or intrinsic or (middle adj band$1gap)) near (	USPAT; US-PGPUB	2004/06/06
173	BRS	22	((pmos or (p adj channel) or p$1channel) with ((mid$1gap or (mid adj gap) or intrinsic or (middle adj band$1gap)) near2	USPAT; US-PGPUB	2004/06/06

File View Edit Tools Window Help

Type	Hits	Search Text	DBs	Time Stamp
173	BRS	22	((pmos or (p adj channel) or p$1channel) with ((mid$1gap or (mid adj gap) or intrinsic or (middle adj band$1gap)) near2	USPAT; US-PGPUB	2004/06/06
174	BRS	15	(((pmos or (p adj channel) or p$1channel) with ((mid$1gap or (mid adj gap) or intrinsic or (middle adj band$1gap)) near2	USPAT; US-PGPUB	2004/06/06
175	BRS	8	((((pmos or (p adj channel) or p$1channel) with ((mid$1gap or (mid adj gap) or intrinsic or (middle adj band$1gap)) near	USPAT; US-PGPUB	2004/06/06
176	BRS	7	("3673471"	USPAT; US-PGPUB	2004/06/06
177	BRS	10	((((pmos or (p adj channel) or p$1channel) with (periphery or peripheral)) and ((nmos or (n adj channel) or n$1channel	USPAT; US-PGPUB	2004/06/06
178	BRS	7	(((pmos or (p adj channel) or p$1channel) with ((mid$1gap or (mid adj gap) or intrinsic or (middle adj band$1gap)) near (	USPAT; US-PGPUB	2004/06/06
179	BRS	35	((gate or electrode) with (mid$1gap or (mid adj gap) or (middle adj band$1gap)))	EPO; JPO; DERWE	2004/06/06
180	BRS	30	(((gate or electrode) with (mid$1gap or (mid adj gap) or (middle adj band$1gap)))) and (@ad<20030828 or @rlad<20	EPO; JPO; DERWE	2004/06/08
181	BRS	3	((gate near2 ("both" adj (impurity$1types or ((impurity or conductivity) adj type) or conductivity$1types))) not ((gate near (	USPAT; US-PGPUB	2004/06/08
182	BRS	9	(gate near3 ("both" adj (impurity$1types or ((impurity or conductivity) adj type) or conductivity$1types)))	USPAT; US-PGPUB	2004/06/08
183	BRS	0	(electrode near ("both" adj (impurity$1types or ((impurity or conductivity) adj type) or conductivity$1types)))	USPAT; US-PGPUB	2004/06/08
184	BRS	0	(electrode near2 ("both" adj (impurity$1types or ((impurity or conductivity) adj type) or conductivity$1types)))	USPAT; US-PGPUB	2004/06/08
185	BRS	5	(electrode near3 ("both" adj (impurity$1types or ((impurity or conductivity) adj type) or conductivity$1types)))	USPAT; US-PGPUB	2004/06/08
186	BRS	5	((electrode near3 ("both" adj (impurity$1types or ((impurity or conductivity) adj type) or conductivity$1types))) and (@ad<	USPAT; US-PGPUB	2004/06/08
187	BRS	0	((((pmos or (p adj channel) or p$1channel) with ((mid$1gap or (mid adj gap) or intrinsic or (middle adj band$1gap)) near	USPAT; US-PGPUB	2004/06/08
188	BRS	2	(gate near ("both" adj (impurity$1types or ((impurity or conductivity) adj type) or conductivity$1types)))	USPAT; US-PGPUB	2004/06/08
189	BRS	4	(((gate near3 ("both" adj (impurity$1types or ((impurity or conductivity) adj type) or conductivity$1types)))) not (((gate near	USPAT; US-PGPUB	2004/06/08
190	BRS	0	(gate adj (doped or implanted or doping or implanting) adj ("opposite" adj (impurity$1types or ((impurity or conductivity) adj	USPAT; US-PGPUB	2004/06/08
191	BRS	3	(gate adj (doped or implanted or doping or implanting or dope or implant) adj ("opposite" adj (impurity$1types or ((impurity	USPAT; US-PGPUB	2004/06/08
192	BRS	4	((gate near3 ("both" adj (impurity$1types or ((impurity or conductivity) adj type) or conductivity$1types))) not (((gate near	USPAT; US-PGPUB	2004/06/08
193	BRS	24	(gate with ("both" adj (impurity$1types or ((impurity or conductivity) adj type) or conductivity$1types)))	USPAT; US-PGPUB	2004/06/08
194	BRS	24	((gate with ("both" adj (impurity$1types or ((impurity or conductivity) adj type) or conductivity$1types))) and (@ad<20030	USPAT; US-PGPUB	2004/06/08
195	BRS	1	"5252501".PN.	USPAT	2004/06/08
196	BRS	1	"5750424".PN.	USPAT	2004/06/08
197	BRS	1	"5985743".PN.	USPAT	2004/06/08
198	BRS	1	"6207538".PN.	USPAT	2004/06/08
199	BRS	1	"6417038".PN.	USPAT	2004/06/08
200	BRS	1	"5324685".PN.	USPAT	2004/06/08
201	BRS	1	"5350939".PN.	USPAT	2004/06/08
202	BRS	1	"5589410".PN.	USPAT	2004/06/08
203	BRS	1	"5990535".PN.	USPAT	2004/06/08
204	BRS	1	"6043114".PN.	USPAT	2004/06/08
205	BRS	11	(((((gate with ("both" adj (impurity$1types or ((impurity or conductivity) adj type) or conductivity$1types))) and (@ad<2003	USPAT; US-PGPUB	2004/06/08
206	BRS	5	(((dram or (dynamic adj (ram or random))).ab.) and ((@ad<20030828 or @rlad<20030828) and ((257/$3.cor.) or (438/$3.	USPAT; US-PGPUB	2004/06/08
207	BRS	0	((dram or (dynamic adj (ram or random))).ab.) and ((boron with ((n$1type or (n adj type)) adj gate)and (@ad<20030828	USPAT; US-PGPUB	2004/06/08
208	BRS	6	((dram or (dynamic adj (ram or random)))) and ((boron with ((n$1type or (n adj type)) adj gate))and (@ad<20030828 or	USPAT; US-PGPUB	2004/06/08
209	BRS	8	(((boron or b)with ((n$1type or (n adj type)) adj gate))and (@ad<20030828 or @rlad<20030828) and ((257/$3.cor.) or (43	USPAT; US-PGPUB	2004/06/08
210	BRS	6	((gate with "both" with boron with phosphorus) and (@ad<20030828 or @rlad<20030828) and ("both" near (boron or phos	USPAT; US-PGPUB	2004/06/22
211	BRS	11	(gate with "both" with boron with phosphorus) and (@ad<20030828 or @rlad<20030828)) and ("both" near2 (boron or pho	USPAT; US-PGPUB	2004/06/22
212	BRS	5	(((gate with "both" with boron with phosphorus) and (@ad<20030828 or @rlad<20030828)) and ("both" near2 (boron or ph	USPAT; US-PGPUB	2004/06/22
213	BRS	5	(gate near2 ("both" adj (impurity$1types or ((impurity or conductivity) adj type) or conductivity$1types)))	USPAT; US-PGPUB	2004/06/22
214	BRS	0	(pmos with ("both" adj (impurity$1types or ((impurity or conductivity) adj type) or conductivity$1types)) not nmos)	USPAT; US-PGPUB	2004/06/22
215	BRS	0	(p$1channel with ("both" adj (impurity$1types or ((impurity or conductivity) adj type) or conductivity$1types)) not n$1channel	USPAT; US-PGPUB	2004/06/22
216	BRS	0	((n adj channel) with ("both" adj (impurity$1types or ((impurity or conductivity) adj type) or conductivity$1types)) not (n adj c	USPAT; US-PGPUB	2004/06/22

	Type	Hits	Search Text	DBs	Time Stamp
216	BRS	0	((p adj channel) with ("both" adj (impurity$1types or ((impurity or conductivity) adj type) or conductivity$1types)) not (n adj c	USPAT; US-PGPUB	2004/06/22
217	BRS	1	((p adj type) with ("both" adj (impurity$1types or ((impurity or conductivity) adj type) or conductivity$1types)) not (n adj type)	USPAT; US-PGPUB	2004/06/22
218	BRS	0	(pmos with "both" with boron with phosphorus not nmos) and (@ad<20030828 or @rlad<20030828)	USPAT; US-PGPUB	2004/06/22
219	BRS	0	(p$1channel with "both" with boron with phosphorus not n$1channel) and (@ad<20030828 or @rlad<20030828)	USPAT; US-PGPUB	2004/06/22
220	BRS	1	(p adj type) with "both" with boron with phosphorus not (n adj type)) and (@ad<20030828 or @rlad<20030828)	USPAT; US-PGPUB	2004/06/22
221	BRS	16	("4249968"	USPAT; US-PGPUB	2004/06/27
222	BRS	7	("4559694"	USPAT; US-PGPUB	2004/06/27
223	BRS	6	(((((third or "3rd") adj (threshold adj voltage))) and (@ad<20030828 or @rlad<20030828)) and ((257/$3.cor.) or (438/$3.c	USPAT; US-PGPUB	2004/06/27
224	BRS	0	(((third or "3rd") adj (threshold adj voltage)) and (((nmos or n$1channel) with (p$1type adj gate)))	USPAT; US-PGPUB	2004/06/27
225	BRS	7	(fermi with (p$1type adj gate))	USPAT; US-PGPUB	2004/06/27
226	BRS	2	((nmos or n$1channel) with (p$1type adj gate)) and (((pmos or p$1channel) with sram))	USPAT; US-PGPUB	2004/06/27
227	BRS	1	"6031267".PN.	USPAT	2004/06/27
228	BRS	1	"5804477".PN.	USPAT	2004/06/27
229	BRS	1	"5780330".PN.	USPAT	2004/06/27
230	BRS	5	((third or "3rd") adj (gate)) and (((nmos or n$1channel) with (p$1type adj gate)))	USPAT; US-PGPUB	2004/06/27
231	BRS	9	((third or "3rd") adj (gate)) and ((fermi with p$1type))	USPAT; US-PGPUB	2004/06/27
232	BRS	9	(((third or "3rd") adj (gate)) and ((fermi with p$1type))) and (@ad<20030828 or @rlad<20030828)	USPAT; US-PGPUB	2004/07/08
233	BRS	8	(((third or "3rd") adj gate) with (work$1function or (work adj function) or fermi))	USPAT; US-PGPUB	2004/07/08
234	BRS	5	("5436178"|"5093701"|"5801427"|"6265258"|"6376888"|"6265258"|"6376888").PN.	USPAT; US-PGPUB	2004/07/08
235	BRS	5	("5436178" "5093701" "5801427" "6265258" "6376888"6265258" "6376888").PN.	USPAT; US-PGPUB	2004/07/08
236	BRS	19	"5780330" and (@ad<20030828 or @rlad<20030828)	USPAT; US-PGPUB	2004/07/08
237	BRS	13	((((third or "3rd") adj (work$1function or (work adj function) or fermi)) and (@ad<20030828 or @rlad<20030828))	USPAT; US-PGPUB	2004/07/08
238	BRS	23	((((third or "3rd" or three) adj (work$1function or (work adj function) or fermi))) and (@ad<20030828 or @rlad<20030828)	USPAT; US-PGPUB	2004/07/08
239	BRS	4	((((third or "3rd" or three) near (work$1function or (work adj function) or fermi))) and (@ad<20030828 or @rlad<20030828	USPAT; US-PGPUB	2004/07/08
240	BRS	6	("4743953"	USPAT; US-PGPUB	2004/07/08
241	BRS	1	(("4743953"	USPAT; US-PGPUB	2004/07/08
242	BRS	3	((third or "3rd" or three) adj different adj (work$1function or (work adj function) or fermi))	USPAT; US-PGPUB	2004/07/08
243	BRS	3	"10189966"	JPO	2004/07/08
244	BRS	23	((third or "3rd" or three) adj (work$1function or (work adj function) or fermi))	USPAT; US-PGPUB	2004/07/08
245	BRS	17	(((third or "3rd" or three) near (work$1function or (work adj function) or fermi))) and (@ad<20030828 or @rlad<20030828)	USPAT; US-PGPUB	2004/07/08
246	BRS	7	((third or "3rd" or three) adj (gate or electrode)) and ((((third or "3rd" or three) adj different adj (threshold or "v.sub.t" or vt)	USPAT; US-PGPUB	2004/07/08
247	BRS	0	(((@ad<20030828 or @rlad<20030828) and (257/391,392,402.ccls.) and ((third or "3rd" or three) adj different adj (work$1	USPAT; US-PGPUB	2004/07/08
248	BRS	7	((@ad<20030828 or @rlad<20030828) and (257/391,392,402.ccls.)) and ((third or "3rd" or three) adj different adj (thresho	USPAT; US-PGPUB	2004/07/08
249	BRS	0	(((third or "3rd" or three) adj (gate or electrode)) and ((@ad<20030828 or @rlad<20030828) and (257/391,392,402.ccls.))	USPAT; US-PGPUB	2004/07/08
250	BRS	0	((@ad<20030828 or @rlad<20030828) and (257/391,392,402.ccls.) and ((third or "3rd" or three) adj different adj (thresho	USPAT; US-PGPUB	2004/07/08
251	BRS	9	((third or "3rd" or three) adj (gate or electrode)) and ((((third or "3rd" or three) adj (threshold or "v.sub.t" or vt)) and (@a	USPAT; US-PGPUB	2004/07/08
252	BRS	13	((third or "3rd" or three) adj (transistor or mosfet or fet or misfet or igfet)) and ((((third or "3rd" or three) adj (threshold or	USPAT; US-PGPUB	2004/07/08
253	BRS	0	((@ad<20030828 or @rlad<20030828) and (257/391,392,402.ccls.) and ((third or "3rd" or three) adj (work$1function or (	USPAT; US-PGPUB	2004/07/08
254	BRS	0	((((gate near (doped or doping or dope))) and ((@ad<20030828 or @rlad<20030828) and (257/391,392,402.ccls.)) and (	USPAT; US-PGPUB	2004/07/08
255	BRS	0	((((gate near (doped or doping or dope))) and ((@ad<20030828 or @rlad<20030828) and (257/391,392,402.ccls.)) and (	USPAT; US-PGPUB	2004/07/08
256	BRS	0	((((gate near (doped or doping or dope))) and ((@ad<20030828 or @rlad<20030828) and (257/391,392,402.ccls.)) and (	USPAT; US-PGPUB	2004/07/08
257	BRS	7	((((gate near (doped or doping or dope))) and ((@ad<20030828 or @rlad<20030828) and (257/391,392,402.ccls.)) and (	USPAT; US-PGPUB	2004/07/08
258	BRS	23	((third or "3rd" or three) adj (work$1function or (work adj function) or fermi))	USPAT; US-PGPUB	2004/07/08
259	BRS	24	(((third or "3rd" or three) adj different adj (threshold or "v.sub.t" or vt))) and (@ad<20030828 or @rlad<20030828) and ((	USPAT; US-PGPUB	2004/07/08

File View Edit Tools Window Help

	Type	Hits	Search Text	DBs	Time Stamp
259	BRS	24	((_(third or "3rd" or three) adj different adj (threshold or "v.sub.t" or vt))) and ((@ad<20030828 or @rlad<20030828) and ((2	USPAT; US-PGPUB	2004/07/08
260	BRS	0	(((third or "3rd" or three) adj (work$1function or (work adj function) or fermi))) and ((third or "3rd" or three) adj (gate))	USPAT; US-PGPUB	2004/07/08
261	BRS	8	(((@ad<20030828 or @rlad<20030828) and ((((third or "3rd" or three) adj_(threshold or "v.sub.t" or vt)) and ((third or "3r	USPAT; US-PGPUB	2004/07/08
262	BRS	0	(((gate near (doped or doping or dope)) and ((@ad<20030828 or @rlad<20030828) and (257/391,392,402.ccls.)))_and (	USPAT; US-PGPUB	2004/07/08
263	BRS	14	(((_(gate near (doped or doping or dope)) with (threshold or "v.sub.t" or vt))) and (@ad<20030828 or @rlad<20030828) an	USPAT; US-PGPUB	2004/07/08
264	BRS	5		USPAT; US-PGPUB	2004/07/08
265	BRS	20	(((_(fermi) with (threshold or "v.sub.t" or vt))) and ((@ad<20030828 or @rlad<20030828) and ((257/$3.cor.) or (438/$3.cor.	USPAT; US-PGPUB	2004/07/08
266	BRS	0	((third or "3rd") adj (mosfet or transistor)) and (((nmos or n$1channel) with (p$1type adj gate)))	USPAT; US-PGPUB	2004/07/08
267	BRS	34	(memory with ((p$1type or (p adj type)) adj gate))	USPAT; US-PGPUB	2004/07/08
268	BRS	23	((memory with ((p$1type or (p adj type)) adj gate))) and ((@ad<20030828 or @rlad<20030828) and ((257/$3.cor.) or (438	USPAT; US-PGPUB	2004/07/08
269	BRS	2	((third or "3rd" or three) adj (misfet or fet or igfet or mosfet or transistor)) and (((memory with ((p$1type or (p adj type)) a	USPAT; US-PGPUB	2004/07/08
270	BRS	9	(memory with "ev" with (poly$1si or (poly adj (si or silicon)) or poly$1silicon)) and ((@ad<20030828 or @rlad<20030828)	USPAT; US-PGPUB	2004/07/09
271	BRS	3	(peripheral with "ev" with (poly$1si or (poly adj (si or silicon)) or poly$1silicon)) and ((@ad<20030828 or @rlad<20030828	USPAT; US-PGPUB	2004/07/09
272	BRS	5	("6362047"|"6444523"|"6531353"|"20020072156"|"20030011017").PN.	USPAT; US-PGPUB	2004/07/09
273	BRS	2	("6358787"|"6461959").PN.	USPAT; US-PGPUB	2004/07/09
274	BRS	1	peripheral and (memory with "ev" with (poly$1si or (poly adj (si or silicon)) or poly$1silicon)) and ((@ad<20030828 or @rla	USPAT; US-PGPUB	2004/07/09
275	BRS	5	((438/231,232.ccls.) and (@ad<20030828 or @rlad<20030828)) and ((gate or electrode) with "ev")	USPAT; US-PGPUB	2004/07/09
276	BRS	18	peripheral and (((memory with ((p$1type or (p adj type)) adj (poly$1si or (poly adj (si or silicon)) or poly$1silicon))) and (	USPAT; US-PGPUB	2004/07/09
277	BRS	1	((third or "3rd" or three) adj (misfet or fet or igfet or mosfet or transistor)) and (((memory with ((p$1type or (p adj type)) a	USPAT; US-PGPUB	2004/07/09
278	BRS	0	((438/231,232.ccls.) and (@ad<20030828 or @rlad<20030828)) and (memory with ((p$1type or (p adj type)) adj (poly$1si	USPAT; US-PGPUB	2004/07/09
279	BRS	15	((third or "3rd" or three) adj (misfet or fet or igfet or mosfet or transistor)) and ((438/231,232.ccls.) and (@ad<20030828	USPAT; US-PGPUB	2004/07/09
280	BRS	30	((third or "3rd" or three) adj (misfet or fet or igfet or mosfet or transistor)) and (counter$1doping or counter$1dope or cou	USPAT; US-PGPUB	2004/07/09
281	BRS	30	(((third or "3rd" or three) adj (misfet or fet or igfet or mosfet or transistor)) and (counter$1doping or counter$1dope or cou	USPAT; US-PGPUB	2004/07/09
282	BRS	13	((third or "3rd" or three) adj (misfet or fet or igfet or mosfet or transistor)) and ((counter$1doping or counter$1dope or (co	USPAT; US-PGPUB	2004/07/09
283	BRS	31	((((counter$1doping or counter$1dope or (counter adj (doping or dope or doped)) or counter$1doped) near (gate or electro	USPAT; US-PGPUB	2004/07/09
284	BRS	11	(((((counter$1doping or counter$1dope or (counter adj (doping or dope or doped)) or counter$1doped) near (gate or electr	USPAT; US-PGPUB	2004/07/09
285	BRS	3	(438/231,232.ccls.) and (((((counter$1doping or counter$1dope or (counter adj (doping or dope or doped)) or counter$1dop	USPAT; US-PGPUB	2004/07/09
286	BRS	20	((((counter$1doping or counter$1dope or (counter adj (doping or dope or doped)) or counter$1doped) near (gate or electro	USPAT; US-PGPUB	2004/07/09
287	BRS	5	(((((counter$1doping or counter$1dope or (counter adj (doping or dope or doped)) or counter$1doped) near2 (gate or elect	USPAT; US-PGPUB	2004/07/09
288	BRS	25	((((counter$1doping or counter$1dope or (counter adj (doping or dope or doped)) or counter$1doped) near2 (gate or electr	USPAT; US-PGPUB	2004/07/09
289	BRS	20	(((((counter$1doping or counter$1dope or (counter adj (doping or dope or doped)) or counter$1doped) near2 (gate or elect	USPAT; US-PGPUB	2004/07/09
290	BRS	15	((((((counter$1doping or counter$1dope or (counter adj (doping or dope or doped)) or counter$1doped) near2 (gate or elec	USPAT; US-PGPUB	2004/07/09
291	BRS	13	(((third or "3rd" or three) adj (misfet or fet or igfet or mosfet or transistor)) and ((counter$1doping or counter$1dope or (c	USPAT; US-PGPUB	2004/07/09
292	BRS	5	((third or "3rd" or three) adj (misfet or fet or igfet or mosfet or transistor)) and (((((counter$1doping or counter$1dope or (	USPAT; US-PGPUB	2004/07/09
293	BRS	2	"6448121"	USPAT; US-PGPUB	2004/07/10
294	BRS	19	(((cmos with (single$1gate or (single adj gate)))) and (@ad<20030828 or @rlad<20030828)) and (dram or (dynamic adj (r	USPAT; US-PGPUB	2004/07/10
295	BRS	18	(((gate with ("both" adj (impurity$1types or ((impurity or conductivity) adj type) or conductivity$1types)))) and (@ad<20030	USPAT; US-PGPUB	2004/07/10
296	BRS	24	((((cmos with (single$1mask or single$1masking or (single adj (mask or masking))))) and (@ad<20030828 or @rlad<2003	USPAT; US-PGPUB	2004/07/10
297	BRS	5	((cmos with (single$1mask or single$1masking or (single adj (mask or masking))))) and (@ad<20030828 or @rlad<2003	USPAT; US-PGPUB	2004/07/10
298	BRS	2	(gate near ("both" adj (impurity$1types or ((impurity or conductivity) adj type) or conductivity$1types)))	USPAT; US-PGPUB	2004/07/10
299	BRS	5	(gate near2 ("both" adj (impurity$1types or ((impurity or conductivity) adj type) or conductivity$1types)))	USPAT; US-PGPUB	2004/07/10
300	BRS	0	(peripheral with fermi) and ((array or cell or memory) with fermi)	USPAT; US-PGPUB	2004/07/11
301	BRS	13	((peripheral with (work$1function or (work adj function) or fermi)) and ((array or cell or memory) with (work$1function or (w	USPAT; US-PGPUB	2004/07/11
302	BRS	19	"5780330" and ((@ad<20030828 or @rlad<20030828)	USPAT; US-PGPUB	2004/07/11

File View Edit Tools Window Help

	Type	Hits	Search Text	DBs	Time Stamp
302	BRS	19	"5780330" and (@ad<20030828 or @rlad<20030828)	USPAT; US-PGPUB	2004/07/11
303	BRS	30	(US-6693333-$ or US-6465305-$ or US-6355531-$ or US-6492690-$ or US-5998828-$ or US-6518130-$ or US-6190952-$	USPAT; US-PGPUB	2004/07/11
304	BRS	3	((US-6693333-$ or US-6465305-$ or US-6355531-$ or US-6492690-$ or US-5998828-$ or US-6518130-$ or US-6190952-	USPAT; US-PGPUB	2004/07/11
305	BRS	22	(doping with fermi with gate) not (fermi adj fet)	USPAT; US-PGPUB	2004/07/11
306	BRS	0	(((dram or (dynamic adj (ram or random))) and (fermi with (gate or electrode))) and ((@ad<20030828 or @rlad<20030828)	USPAT; US-PGPUB	2004/07/11
307	BRS	25	(((dram or (dynamic adj (ram or random))) and ((@ad<20030828 or @rlad<20030828) and ((high adj (threshold or vt or "v	USPAT; US-PGPUB	2004/07/11
308	BRS	1	((single adj gate adj (process or processing or mask or masking)) with (periphery or peripheral or support or logic))	USPAT; US-PGPUB	2004/07/11
309	BRS	0	((single adj gate adj (process or processing or mask or masking)) with cmos) and (((cmos with (periphery or peripheral	USPAT; US-PGPUB	2004/07/11
310	BRS	0	((single adj gate adj (process or processing or mask or masking))) and (((cmos with (periphery or peripheral or support	USPAT; US-PGPUB	2004/07/11
311	BRS	17	((counter$1doping or counter$1dope or (counter adj (doping or dope or doped)) or counter$1doped) with (gate or electrod	USPAT; US-PGPUB	2004/07/11
312	BRS	4	((dram or (dynamic adj (ram or random))) and (@ad<20030828 or @rlad<20030828) and ((high adj (threshold or vt or "v	USPAT; US-PGPUB	2004/07/11
313	BRS	5	((dram or (dynamic adj (ram or random))) and (@ad<20030828 or @rlad<20030828) and ((high adj (threshold or vt or "v	USPAT; US-PGPUB	2004/07/11
314	BRS	12	((dram or (dynamic adj (ram or random))) and (@ad<20030828 or @rlad<20030828) and ((high adj (threshold or vt or "v	USPAT; US-PGPUB	2004/07/11
315	BRS	28	(((dram or (dynamic adj (ram or random))) and (@ad<20030828 or @rlad<20030828) and ((high adj (threshold or vt or "v	USPAT; US-PGPUB	2004/07/11
316	BRS	13	(peripheral with (work$1function or (work adj function) or fermi)) and ((array or cell or memory) with (work$1function or (w	USPAT; US-PGPUB	2004/07/12
317	BRS	10	((((dram or (dynamic adj (ram or random))) and (@ad<20030828 or @rlad<20030828) and ((high adj (threshold or vt or "	USPAT; US-PGPUB	2004/07/12
318	BRS	22	((memory or array) with (p$1type adj gate))	USPAT; US-PGPUB	2004/07/12
319	BRS	15	((memory or array) with (p$1type adj gate)) and (dram or (dynamic adj (ram or random)))	USPAT; US-PGPUB	2004/07/12
320	BRS	15	((((memory or array) with (p$1type adj gate))) and (dram or (dynamic adj (ram or random)))) and ((@ad<20030828 or @	USPAT; US-PGPUB	2004/07/12
321	BRS	4	((memory or array) with ("p+" adj gate))	USPAT; US-PGPUB	2004/07/12
322	BRS	15	((memory or array) with ("p+" near gate))	USPAT; US-PGPUB	2004/07/12
323	BRS	6	((((memory or array) with ("p+" near gate))) and (dram or (dynamic adj (ram or random)))) and ((@ad<20030828 or @rla	USPAT; US-PGPUB	2004/07/12
324	BRS	24	(((memory or array) with ("p+" near2 gate))) and (dram or (dynamic adj (ram or random)))	USPAT; US-PGPUB	2004/07/12
325	BRS	0	((memory or array) with "p+" with gate with fermi)	USPAT; US-PGPUB	2004/07/12
326	BRS	6	(((memory or array) with ("p+" near gate))) and (dram or (dynamic adj (ram or random)))	USPAT; US-PGPUB	2004/07/12
327	BRS	24	((((memory or array) with ("p+" near2 gate))) and (dram or (dynamic adj (ram or random)))) and ((@ad<20030828 or @rl	USPAT; US-PGPUB	2004/07/12
328	BRS	0	(((memory or array) with "p+" with gate) same fermi	USPAT; US-PGPUB	2004/07/12
329	BRS	31	((threshold with "p+" with gate)) and ((memory or array) with threshold)	USPAT; US-PGPUB	2004/07/12
330	BRS	20	((((threshold with "p+" with gate)) and ((memory or array) with threshold)) and (dram or (dynamic adj (ram or random))))	USPAT; US-PGPUB	2004/07/12
331	BRS	0	((threshold with "p+" with gate) same fermi) and ((memory or array) with threshold)	USPAT; US-PGPUB	2004/07/12
332	BRS	20	(((threshold with "p+" with gate)) and ((memory or array) with threshold)) and (dram or (dynamic adj (ram or random)))	USPAT; US-PGPUB	2004/07/12
333	BRS	1	((threshold with "p+" with gate with high)) and (dram or (dynamic adj (ram or random)))	USPAT; US-PGPUB	2004/07/12
334	BRS	35	(US-6693333-$ or US-6465305-$ or US-6355531-$ or US-6492690-$ or US-5998828-$ or US-6518130-$ or US-6190952-$	USPAT; US-PGPUB	2004/07/12
335	BRS	3	(((threshold with "p+" with gate)) and ((memory or array) with threshold)) and (dram or (dynamic adj (ram or random))).ab	USPAT; US-PGPUB	2004/07/12
336	BRS	33	((US-6693333-$ or US-6465305-$ or US-6355531-$ or US-6492690-$ or US-5998828-$ or US-6518130-$ or US-6190952-	USPAT; US-PGPUB	2004/07/12
337	BRS	18	((((US-6693333-$ or US-6465305-$ or US-6355531-$ or US-6492690-$ or US-5998828-$ or US-6518130-$ or US-6190952	USPAT; US-PGPUB	2004/07/12
338	BRS	14	((((US-6693333-$ or US-6465305-$ or US-6355531-$ or US-6492690-$ or US-5998828-$ or US-6518130-$ or US-619095	USPAT; US-PGPUB	2004/07/12
339	BRS	3	((((threshold with "p+" with gate)) and ((memory or array) with threshold)) and (dram or (dynamic adj (ram or random))).a	USPAT; US-PGPUB	2004/07/12
340	BRS	4	((US-6693333-$ or US-6465305-$ or US-6355531-$ or US-6492690-$ or US-5998828-$ or US-6518130-$ or US-6190952	USPAT; US-PGPUB	2004/07/12
341	BRS	0	((((threshold with p$1type with nmos with gate)) and ((@ad<20030828 or @rlad<20030828)) and (dram or (dynamic adj	USPAT; US-PGPUB	2004/07/12
342	BRS	19	(((threshold with p$1type with nmos with gate)) and ((@ad<20030828 or @rlad<20030828)) and (dram or (dynamic adj	USPAT; US-PGPUB	2004/07/12
343	BRS	16	((((threshold with p$1type with nmos with gate)) and ((@ad<20030828 or @rlad<20030828)) and (dram or (dynamic adj	USPAT; US-PGPUB	2004/07/12
344	BRS	33	((gate near (doped or doping or impurity or dope)) with (threshold or vt or "v.sub.t"))) and (gate near p$1type)	USPAT; US-PGPUB	2004/07/12
345	BRS	17	(((((p$1channel or nmos) with (p$1type near gate))) and ((@ad<20030828 or @rlad<20030828)) and (p$1type with gate	USPAT; US-PGPUB	2004/07/12

File   View   Edit   Tools   Window   Help

	Type	Hits	Search Text	DBs	Time Stamp
345	BRS	17	(((((n$1channel or nmos) with (p$1type near gate))) and (@ad<20030828 or @rlad<20030828)) and (p$1type with gate	USPAT; US-PGPUB	2004/07/12
346	BRS	0	(((threshold or vt or "v.sub.t") with (peripheral or logic) with (array or memory) with fermi)	USPAT; US-PGPUB	2004/07/12
347	BRS	0	(((threshold or vt or "v.sub.t") with (peripheral or logic) with (array or memory)) same fermi)	USPAT; US-PGPUB	2004/07/24
348	BRS	23	(((threshold or vt or "v.sub.t") near fermi)) not (fermi.ti.)	USPAT; US-PGPUB	2004/07/24
349	BRS	10	((fermi) with (memory or array) with (logic or peripheral))	USPAT; US-PGPUB	2004/07/24
350	BRS	0	(((threshold or vt or "v.sub.t") with (lower) with (memory or array) with (logic or peripheral))) and (257/@96.cor.)	USPAT; US-PGPUB	2004/07/24
351	BRS	3	(((threshold or vt or "v.sub.t") with (lower) with (memory or array) with (logic or peripheral))) and (257/296.cor.)	USPAT; US-PGPUB	2004/07/24
352	BRS	9	(((threshold or vt or "v.sub.t") with (lower) with (memory or array) with (logic or peripheral))) and (257/296.ccls.)	USPAT; US-PGPUB	2004/07/24
353	BRS	16	(((threshold or vt or "v.sub.t") with (lowest) with (memory or array) with (logic or peripheral))	USPAT; US-PGPUB	2004/07/24
354	BRS	10	((((dram or (dynamic adj (ram or random))) and (@ad<20030828 or @rlad<20030828) and (high adj (threshold or vt or "	USPAT; US-PGPUB	2004/07/24
355	BRS	13	((dram or (dynamic adj (ram or random))).ab.) and (((threshold or vt or "v.sub.t") with (low) with (memory or array) with	USPAT; US-PGPUB	2004/07/24
356	BRS	2	((dram or (dynamic adj (ram or random))).ti.) and (((low adj (threshold or vt or "v.sub.t")) with (memory or array) with (logi	USPAT; US-PGPUB	2004/07/24
357	BRS	3	((dram or (dynamic adj (ram or random))).ab.) and (((low adj (threshold or vt or "v.sub.t")) with (memory or array) with (lo	USPAT; US-PGPUB	2004/07/24
358	BRS	3	((dram or (dynamic adj (ram or random))).ti.) and (((higher adj (threshold or vt or "v.sub.t")) with (memory or array) with (l	USPAT; US-PGPUB	2004/07/24
359	BRS	3	((dram or (dynamic adj (ram or random))).clm.) and (((higher adj (threshold or vt or "v.sub.t")) with (memory or array) with	USPAT; US-PGPUB	2004/07/24
360	BRS	1	((dram or (dynamic adj (ram or random))).ab.) and (((higher adj (threshold or vt or "v.sub.t")) with (memory or array) with (	USPAT; US-PGPUB	2004/07/24
361	BRS	12	((cmos with (logic or peripheral)) same ((n$1channel or (n adj channel) or nmos) with (memory or array)) same (reason or	USPAT; US-PGPUB	2004/07/24
362	BRS	3	((threshold or vt or "v.sub.t")) with (memory or array) with (logic or peripheral)) and ((dram or (dynamic adj (ram or rando	USPAT; US-PGPUB	2004/07/24
363	BRS	7	((cmos near (logic or peripheral)) same ((n$1channel or (n adj channel) or nmos) near (memory or array)))	USPAT; US-PGPUB	2004/07/24
364	BRS	30	(((cmos with (logic or peripheral)) same ((n$1channel or (n adj channel) or nmos) with (memory or array))) and (((thresho	USPAT; US-PGPUB	2004/07/24
365	BRS	35	((cmos with (logic or peripheral)) same ((n$1channel or (n adj channel) or nmos) with (memory or array))) and (((threshol	USPAT; US-PGPUB	2004/07/24
366	BRS	31	((dram or (dynamic adj (ram or random))) and (((higher adj (threshold or vt or "v.sub.t")) with (memory or array) with (logi	USPAT; US-PGPUB	2004/07/24
367	BRS	12	(((cmos with (logic or peripheral)) same ((n$1channel or (n adj channel) or nmos) with (memory or array)) same (reason or	USPAT; US-PGPUB	2004/07/24
368	BRS	35	(((threshold or vt or "v.sub.t") with (memory or array) with (logic or peripheral)) and ((((cmos with (logic or peripheral)) sa	USPAT; US-PGPUB	2004/07/24
369	BRS	32	((logic or peripheral) with (memory or array) with (gate near (doped or doping or impurity or dope)))	USPAT; US-PGPUB	2004/07/24
370	BRS	22	((dram or (dynamic adj (ram or random))) and ((((logic or peripheral) with (memory or array) with (gate near (doped or d	USPAT; US-PGPUB	2004/07/24
371	BRS	10	((threshold or vt or "v.sub.t") with gate) and (((dram or (dynamic adj (ram or random)))) and ((((logic or peripheral) with (	USPAT; US-PGPUB	2004/07/24
372	BRS	0	((triple adj (work$1function or (work adj function))) with (logic or peripheral or support) with (memory or array))	USPAT; US-PGPUB	2004/07/24
373	BRS	0	(triple adj (work$1function or (work adj function)))	USPAT; US-PGPUB	2004/07/24
374	BRS	0	((third adj (work$1function or (work adj function))) with (logic or peripheral or support) with (memory or array)	USPAT; US-PGPUB	2004/07/24
375	BRS	0	(triple adj (work$1function or (work adj function))) same ((logic or peripheral or support) with (memory or array)))	USPAT; US-PGPUB	2004/07/24
376	BRS	0	((third adj (work$1function or (work adj function))) same ((logic or peripheral or support) with (memory or array)))	USPAT; US-PGPUB	2004/07/24
377	BRS	32	(((logic or peripheral) with (memory or array) with (gate near (doped or doping or impurity or dope)))) and (@ad<200308	USPAT; US-PGPUB	2004/07/24
378	BRS	0	((dram or (dynamic adj (ram or random))).ab.) and (((third or "3rd") adj (threshold or vt or "v.sub.t")) with ((logic or peri	USPAT; US-PGPUB	2004/07/24
379	BRS	0	((dram or (dynamic adj (ram or random))).ti.) and (((third or "3rd") adj (threshold or vt or "v.sub.t")) with ((logic or periph	USPAT; US-PGPUB	2004/07/24
380	BRS	0	((dram or (dynamic adj (ram or random))).clm.) and ((((third or "3rd") adj (threshold or vt or "v.sub.t")) with ((logic or peri	USPAT; US-PGPUB	2004/07/24
381	BRS	31	((((dram or (dynamic adj (ram or random)))) and ((((third or "3rd") adj (threshold or vt or "v.sub.t")) with ((logic or periph	USPAT; US-PGPUB	2004/07/24
382	BRS	7	(peripheral or support or logic) with (memory or array) with (threshold or vt or "v.sub.t")) and ((figure with (logic or periphe	USPAT; US-PGPUB	2004/07/25
383	BRS	16	((((peripheral or support or logic) with (memory or array) with (threshold or vt or "v.sub.t") with (higher or lower or greater)	USPAT; US-PGPUB	2004/07/25
384	BRS	3	(dram or (dynamic adj (ram or random))) and ((((peripheral or support or logic) with (memory or array) with (threshold or vt	USPAT; US-PGPUB	2004/07/25
385	BRS	5	((peripheral or support or logic) with (memory or array) with (threshold or vt or "v.sub.t") with (tailor or tailoring or tailored o	USPAT; US-PGPUB	2004/07/25
386	BRS	7	((dram or (dynamic adj (ram or random)).ab.) and (((threshold or vt or "v.sub.t") with (tailor or tailoring or tailored or cust	USPAT; US-PGPUB	2004/07/25
387	BRS	7	(peripheral or support or logic) with (memory or array) with (threshold or vt or "v.sub.t") with gate) and (((dram or (dynami	USPAT; US-PGPUB	2004/08/20
388	BRS	0	((three adj different adj threshold adj voltage) and (@ad<20030828 or @rlad<20030828)) and fermi	USPAT; US-PGPUB	2004/08/20

Ready

	Type	Hits	Search Text	DBs	Time Stamp
388	BRS	0	((three adj different adj threshold adj voltage) and (@ad<20030828 or @rlad<20030828)) and fermi	USPAT; US-PGPUB	2004/08/20
389	BRS	1	((three adj different adj threshold adj voltage) and ((@ad<20030828 or @rlad<20030828)) and (threshold with work)	USPAT; US-PGPUB	2004/08/20
390	BRS	23	(((fermi with (threshold adj voltage))) and (@ad<20030828 or @rlad<20030828)) and dram	USPAT; US-PGPUB	2004/08/20
391	BRS	14	"5153146" "6448121" "6586296"	USPAT; US-PGPUB	2004/08/20
392	BRS	3	(gate adj doped adj both)	USPAT; US-PGPUB	2004/08/20
393	BRS	14	("5153146" "6448121" "6586296") and (@ad<20030828 or @rlad<20030828)	USPAT; US-PGPUB	2004/08/20
394	BRS	12	(((gate with (both adj (conductivity or impurity)))) and ((@ad<20030828 or @rlad<20030828)) and ((257/$3.cor.) or (438/$3	USPAT; US-PGPUB	2004/08/20
395	BRS	4	(((p adj n) or p$1n) adj gate)) and ((257/$3.cor.) or (438/$3.cor.)) and (dram or (dynamic adj (random or ram)))	USPAT; US-PGPUB	2004/08/20
396	BRS	6	((gate near (counter$1dope or counter$1doped or (counter adj (dope or doped or doping or dopant)) or counter$1dopant or	USPAT; US-PGPUB	2004/08/20
397	BRS	5	(memory with (higher adj threshold) with peripheral) and ((257/$3.cor.) or (438/$3.cor.)) and (dram or (dynamic adj (random	USPAT; US-PGPUB	2004/08/20
398	BRS	1	(memory with (high adj threshold) with peripheral) and ((257/$3.cor.) or (438/$3.cor.)) and (dram or (dynamic adj (random o	USPAT; US-PGPUB	2004/08/20
399	BRS	2	((memory with (threshold) with relative with peripheral)) and ((257/$3.cor.) or (438/$3.cor.))	USPAT; US-PGPUB	2004/08/20
400	BRS	3	(memory with (threshold) with relative with peripheral)	USPAT; US-PGPUB	2004/08/20
401	BRS	28	(memory with (threshold) with (dram or (dynamic adj (ram or random))) with peripheral)	USPAT; US-PGPUB	2004/08/20
402	BRS	3	((US-6552401-$ or US-5939743-$ or US-6683353-$ or US-6693333-$ or US-6465305-$ or US-6355531-$ or US-6492690-	USPAT; US-PGPUB	2004/08/20
403	BRS	1	((memory with (threshold) with relative with peripheral)) and ((257/$3.cor.) or (438/$3.cor.)) and (dram or (dynamic adj (ra	USPAT; US-PGPUB	2004/08/20
404	BRS	27	((memory with (threshold) with (dram or (dynamic adj (ram or random))) with peripheral)) and (@ad<20030828 or @rlad<2	USPAT; US-PGPUB	2004/08/20
405	BRS	0	((p$1type adj (poly$1silicon or poly$1si or (poly adj (si or silicon))) adj gate) with memory not (pmos or p$1channel))	USPAT; US-PGPUB	2004/08/20
406	BRS	10	((((p$1type adj (poly$1silicon or poly$1si or (poly adj (si or silicon))) adj gate) with gate not (pmos or p$1channel))) and ((	USPAT; US-PGPUB	2004/08/20
407	BRS	10	(((p$1type adj (poly$1silicon or poly$1si or (poly adj (si or silicon))) adj gate) with gate not (pmos or p$1channel))) and ((2	USPAT; US-PGPUB	2004/08/20
408	BRS	101	((((p$1type adj gate) with gate not (pmos or p$1channel)) and ((poly$1silicon or poly$1si or (poly adj (si or silicon))) with g	USPAT; US-PGPUB	2004/08/20
409	BRS	19	((((p$1type adj gate) with gate not (pmos or p$1channel)) and ((poly$1silicon or poly$1si or (poly adj (si or silicon))) with g	USPAT; US-PGPUB	2004/08/20
410	BRS	1	((p$1type adj (poly$1silicon or poly$1si or (poly adj (si or silicon))) adj gate) with (high or higher) with (nmos or n$1channel	USPAT; US-PGPUB	2004/08/20
411	BRS	2	(((p$1type adj gate) with (high or higher) with (nmos or n$1channel))) and ((poly$1silicon or poly$1si or (poly adj (si or silic	USPAT; US-PGPUB	2004/08/20
412	BRS	14	(p$1type adj gate) with (high or higher) with (nmos or n$1channel))	USPAT; US-PGPUB	2004/08/20
413	BRS	0	(((p$1type adj (poly$1silicon or poly$1si or (poly adj (si or silicon))) adj gate) with (nmos or n$1channel or (n adj channel))	USPAT; US-PGPUB	2004/08/22
414	BRS	0	(((p$1type adj (poly$1silicon or poly$1si or (poly adj (si or silicon))) near gate) with (nmos or n$1channel or (n adj channel)	USPAT; US-PGPUB	2004/08/22
415	BRS	0	(((p$1type adj (poly$1silicon or poly$1si or (poly adj (si or silicon))) near2 gate) with (nmos or n$1channel or (n adj channe	USPAT; US-PGPUB	2004/08/22
416	BRS	0	(((p$1type adj (poly$1silicon or poly$1si or (poly adj (si or silicon))) with gate) with (nmos or n$1channel or (n adj channel))	USPAT; US-PGPUB	2004/08/22
417	BRS	0	(((p$1type adj (poly$1silicon or poly$1si or (poly adj (si or silicon))) with gate) with (nmos or n$1channel or (n adj channel))	USPAT; US-PGPUB	2004/08/22
418	BRS	21	(((p$1type with (poly$1silicon or poly$1si or (poly adj (si or silicon))) with gate) with (nmos or n$1channel or (n adj channel	USPAT; US-PGPUB	2004/08/22
419	BRS	14	(((p$1type with (poly$1silicon or poly$1si or (poly adj (si or silicon))) with gate) with (nmos or n$1channel or (n adj channel	USPAT; US-PGPUB	2004/08/22
420	BRS	1	((p$1type adj gate) with (nmos or n$1channel or (n adj channel)) not (pmos or p$1channel or (p adj channel))) and (@ad	USPAT; US-PGPUB	2004/08/22
421	BRS	20	((p$1type near2 gate) with (nmos or n$1channel or (n adj channel)) not (pmos or p$1channel or (p adj channel))) and (@	USPAT; US-PGPUB	2004/08/22
422	BRS	5	((p$1gate) with (nmos or n$1channel or (n adj channel)) not (pmos or p$1channel or (p adj channel))) and (@ad<200308	USPAT; US-PGPUB	2004/08/22
423	BRS	14	(((p$1type with (poly$1silicon or poly$1si or (poly adj (si or silicon))) with gate) with (nmos or n$1channel or (n adj channel	USPAT; US-PGPUB	2004/08/22
424	BRS	0	(((p$1type adj (poly$1silicon or (poly adj (si or silicon)) or poly$1si) with gate) with (nmos or n$1channel or (n adj channel)	USPAT; US-PGPUB	2004/08/22
425	BRS	0	(((p$1type adj (poly$1silicon or (poly adj (si or silicon)) or poly$1si)) with gate) with (nmos or n$1channel or (n adj channel)	USPAT; US-PGPUB	2004/08/22
426	BRS	0	(((p$1type near (poly$1silicon or (poly adj (si or silicon)) or poly$1si)) with gate) with (nmos or n$1channel or (n adj channel	USPAT; US-PGPUB	2004/08/22
427	BRS	1	"3615934".PN.	USPAT	2004/08/22
428	BRS	1	"3673471".PN.	USPAT	2004/08/22
429	BRS	1	"5674788".PN.	USPAT	2004/08/22
430	BRS	1	"5757204".PN.	USPAT	2004/08/22
431	BRS	1	"5783469".PN.	USPAT	2004/08/22

File   View   Edit   Tools   Window   Help

	Type	Hits	Search Text	DBs	Time Stamp
431	BRS	1	"5783469".PN.	USPAT	2004/08/22
432	BRS	1	"5789780".PN.	USPAT	2004/08/22
433	BRS	1	"3673471".PN.	USPAT	2004/08/22
434	BRS	1	"3355637".PN.	USPAT	2004/08/22
435	BRS	1	"3386016".PN.	USPAT	2004/08/22
436	BRS	1	"3514676".PN.	USPAT	2004/08/22
437	BRS	1	"3519901".PN.	USPAT	2004/08/22
438	BRS	1	"3576478".PN.	USPAT	2004/08/22
439	BRS	1	"3460007".PN.	USPAT	2004/08/22
440	BRS	1	"3386016".PN.	USPAT	2004/08/22
441	BRS	1	"3514676".PN.	USPAT	2004/08/22
442	BRS	22	(((p$1type adj (poly$1silicon or (poly adj (si or silicon)) or poly$1si)) adj gate) with (nmos or n$1channel or (n adj channel)	USPAT; US-PGPUB	2004/08/22
443	BRS	4	(p$1type adj (poly$1silicon or (poly adj (si or silicon)) or poly$1si) adj gate) and "3673471"	USPAT; US-PGPUB	2004/08/22
444	BRS	1	"5691225".PN.	USPAT	2004/08/22
445	BRS	1	"6030862".PN.	USPAT	2004/08/22
446	BRS	1	"6207510".PN.	USPAT	2004/08/22
447	BRS	2	("5953246" "6573575").pn.	USPAT; US-PGPUB	2004/09/18
448	BRS	2	((simultaneous or simultaneously) with (anneal or annealing or annealed or activate or activating or activated) with (phosphor	USPAT; US-PGPUB	2004/09/20
449	BRS	24	(((simultaneous or simultaneously) with (anneal or annealing or annealed or activate or activating or activated) with (phospho	USPAT; US-PGPUB	2004/09/20
450	BRS	2	((((simultaneous or simultaneously) with (anneal or annealing or annealed or activate or activating or activated) with (phosph	USPAT; US-PGPUB	2004/09/20
451	BRS	0	(((simultaneous or simultaneously) with (anneal or annealing or annealed or activate or activating or activated) with (phospho	USPAT; US-PGPUB	2004/09/20
452	BRS	3	((simultaneous or simultaneously) with (anneal or annealing or annealed or activate or activating or activated) with (gate or e	USPAT; US-PGPUB	2004/09/20
453	BRS	3	(((simultaneous or simultaneously) with (anneal or annealing or annealed or activate or activating or activated) with (gate or	USPAT; US-PGPUB	2004/09/20
454	BRS	5	((simultaneous or simultaneously or ("same" adj time)) with (anneal or annealing or annealed or activate or activating or acti	USPAT; US-PGPUB	2004/09/20
455	BRS	0	((simultaneous or simultaneously) with (anneal or annealing or annealed or activate or activating or activated) with (phosphor	USPAT; US-PGPUB	2004/09/20
456	BRS	5	((simultaneous or simultaneously or ("same" adj time)) with (anneal or annealing or annealed or activate or activating or act	USPAT; US-PGPUB	2004/09/20
457	BRS	6	(((simultaneous or simultaneously) with (anneal or annealing or annealed or activate or activating or activated) with (phospho	USPAT; US-PGPUB	2004/09/20
458	BRS	0	(((gate or electrode) with (counter$1dope or counter$1doping or counter$1dopant or (counter adj (dope or doping or dopant	USPAT; US-PGPUB	2004/09/20
459	BRS	0	(((gate or electrode) with (counter$1dope or counter$1doping or counter$1dopant or (counter adj (dope or doping or dopant	USPAT; US-PGPUB	2004/09/20
460	BRS	0	((gate or electrode) with (counter$1dope or counter$1doping or counter$1dopant or (counter adj (dope or doping or dopant	USPAT; US-PGPUB	2004/09/20
461	BRS	2	((gate or electrode) with dual) and (((anneal or annealing or annealed or activate or activating or activated) with (phosphoru	USPAT; US-PGPUB	2004/09/20
462	BRS	16	((anneal or annealing or annealed or activate or activating or activated) with (phosphorus or p) with (boron or b) with (gate o	USPAT; US-PGPUB	2004/09/20
463	BRS	14	(((gate or electrode) with (counter$1dope or counter$1doping or counter$1dopant or (counter adj (dope or doping or dopant	USPAT; US-PGPUB	2004/09/20
464	BRS	14	((gate or electrode) with (counter$1dope or counter$1doping or counter$1dopant or (counter adj (dope or doping or dopant	USPAT; US-PGPUB	2004/09/20
465	BRS	14	((gate or electrode) with (counter$1dope or counter$1doping or counter$1dopant or (counter adj (dope or doping or dopant	USPAT; US-PGPUB	2004/09/20
466	BRS	14	(((gate or electrode) with (counter$1dope or counter$1doping or counter$1dopant or (counter adj (dope or doping or dopant	USPAT; US-PGPUB	2004/09/20
467	BRS	11	((gate or electrode) with (counter$1dope or counter$1doping or counter$1dopant or (counter adj (dope or doping or dopant	USPAT; US-PGPUB	2004/09/20
468	BRS	11	(((gate or electrode) with (counter$1dope or counter$1doping or counter$1dopant or (counter adj (dope or doping or dopant	USPAT; US-PGPUB	2004/09/20
469	BRS	0	((gate or electrode) with (counter$1dope or counter$1doping or counter$1dopant or (counter adj (dope or doping or dopant	USPAT; US-PGPUB	2004/09/20
470	BRS	0	((anneal or annealing or annealed or activate or activating or activated) with (phosphorus or p) with (boron or b) with (gate o	USPAT; US-PGPUB	2004/09/30
471	BRS	0	(((simultaneous or simultaneously) adj (anneal or annealing or annealed or activate or activating or activated or annealing))	USPAT; US-PGPUB	2004/09/30
472	BRS	0	(((simultaneous or simultaneously) adj (anneal or annealing or annealed or activate or activating or activated or annealing))	USPAT; US-PGPUB	2004/09/30
473	BRS	2	((((simultaneous or simultaneously) adj (anneal or annealing or annealed or activate or activating or activated or annealing))	USPAT; US-PGPUB	2004/09/30
474	BRS	20	(((simultaneous or simultaneously) adj (anneal or annealing or annealed or activate or activating or activated or annealing))	USPAT; US-PGPUB	2004/09/30

	Type	Hits	Search Text	DBs	Time Stan*
438	BRS	1	"3576478".PN.	USPAT	2004/08/22
439	BRS	1	"3460007".PN.	USPAT	2004/08/22
440	BRS	1	"3386016".PN.	USPAT	2004/08/22
441	BRS	1	"3514676".PN.	USPAT	2004/08/22
442	BRS	22	(((p$1type adj (poly$1silicon or (poly adj (si or silicon)) or poly$1si)) adj gate) with (nmos or n$1channel or (n adj channel)	USPAT: US-PGPUB	2004/08/22
443	BRS	4	(p$1type adj (poly$1silicon or (poly adj (si or silicon)) or poly$1si) adj gate) and "3673471"	USPAT: US-PGPUB	2004/08/22
444	BRS	1	"5691225".PN.	USPAT	2004/08/22
445	BRS	1	"6030862".PN.	USPAT	2004/08/22
446	BRS	1	"6207510".PN.	USPAT	2004/08/22
447	BRS	2	("5953246" "6573575").pn.	USPAT: US-PGPUB	2004/09/18
448	BRS	2	((simultaneous or simultaneously) with (anneal or annealing or annealed or activate or activating or activated) with (phosphor	USPAT: US-PGPUB	2004/09/20
449	BRS	24	(((simultaneous or simultaneously) with (anneal or annealing or annealed or activate or activating or activated) with (phospho	USPAT: US-PGPUB	2004/09/20
450	BRS	2	((((simultaneous or simultaneously) with (anneal or annealing or annealed or activate or activating or activated) with (phosph	USPAT: US-PGPUB	2004/09/20
451	BRS	0	((simultaneous or simultaneously) with (anneal or annealing or annealed or activate or activating or activated) with (phospho	USPAT: US-PGPUB	2004/09/20
452	BRS	3	(((simultaneous or simultaneously) with (anneal or annealing or annealed or activate or activating or activated) with (gate or e	USPAT: US-PGPUB	2004/09/20
453	BRS	3	(((simultaneous or simultaneously) with (anneal or annealing or annealed or activate or activating or activated) with (gate or	USPAT: US-PGPUB	2004/09/20
454	BRS	5	((simultaneous or simultaneously or ("same" adj time)) with (anneal or annealing or annealed or activate or activating or acti	USPAT: US-PGPUB	2004/09/20
455	BRS	0	(((simultaneous or simultaneously) with (anneal or annealing or annealed or activate or activating or activated) with (phosphor	USPAT: US-PGPUB	2004/09/20
456	BRS	5	((((simultaneous or simultaneously or ("same" adj time)) with (anneal or annealing or annealed or activate or activating or act	USPAT: US-PGPUB	2004/09/20
457	BRS	6	((((simultaneous or simultaneously) with (anneal or annealing or annealed or activate or activating or activated) with (phospho	USPAT: US-PGPUB	2004/09/20
458	BRS	0	(((gate or electrode) with (counter$1dope or counter$1doping or counter$1dopant or (counter adj (dope or doping or dopant	USPAT: US-PGPUB	2004/09/20
459	BRS	0	(((gate or electrode) with (counter$1dope or counter$1doping or counter$1dopant or (counter adj (dope or doping or dopant	USPAT: US-PGPUB	2004/09/20
460	BRS	0	((gate or electrode) with (counter$1dope or counter$1doping or counter$1dopant or (counter adj (dope or doping or dopant	USPAT: US-PGPUB	2004/09/20
461	BRS	2	((gate or electrode) with dual) and (((anneal or annealing or annealed or activate or activating or activated) with (phosphoru	USPAT: US-PGPUB	2004/09/20
462	BRS	16	((anneal or annealing or annealed or activate or activating or activated) with (phosphorus or p) with (boron or b) with (gate o	USPAT: US-PGPUB	2004/09/20
463	BRS	14	(((gate or electrode) with (counter$1dope or counter$1doping or counter$1dopant or (counter adj (dope or doping or dopant	USPAT: US-PGPUB	2004/09/20
464	BRS	14	((gate or electrode) with (counter$1dope or counter$1doping or counter$1dopant or (counter adj (dope or doping or dopant	USPAT: US-PGPUB	2004/09/20
465	BRS	14	((gate or electrode) with (counter$1dope or counter$1doping or counter$1dopant or (counter adj (dope or doping or dopant	USPAT: US-PGPUB	2004/09/20
466	BRS	14	((gate or electrode) with (counter$1dope or counter$1doping or counter$1dopant or (counter adj (dope or doping or dopant	USPAT: US-PGPUB	2004/09/20
467	BRS	11	((gate or electrode) with (counter$1dope or counter$1doping or counter$1dopant or (counter adj (dope or doping or dopant	USPAT: US-PGPUB	2004/09/20
468	BRS	11	(((gate or electrode) with (counter$1dope or counter$1doping or counter$1dopant or (counter adj (dope or doping or dopant	USPAT: US-PGPUB	2004/09/20
469	BRS	0	((gate or electrode) with (counter$1dope or counter$1doping or counter$1dopant or (counter adj (dope or doping or dopant	USPAT: US-PGPUB	2004/09/20
470	BRS	0	((anneal or annealing or annealed or activate or activating or activated) with (phosphorus or p) with (boron or b) with (gate o	USPAT: US-PGPUB	2004/09/30
471	BRS	0	(((simultaneous or simultaneously) adj (anneal or annealing or annealed or activate or activating or activated or annealing))	USPAT: US-PGPUB	2004/09/30
472	BRS	0	((((simultaneous or simultaneously) adj (anneal or annealing or annealed or activate or activating or activated or annealing))	USPAT: US-PGPUB	2004/09/30
473	BRS	2	((((simultaneous or simultaneously) adj (anneal or annealing or annealed or activate or activating or activated or annealing))	USPAT: US-PGPUB	2004/09/30
474	BRS	29	(((simultaneous or simultaneously) adj (anneal or annealing or annealed or activate or activating or activated or annealing))	USPAT: US-PGPUB	2004/09/30
475	BRS	29	(((simultaneous or simultaneously) adj (anneal or annealing or annealed or activate or activating or activated or annealing))	USPAT: US-PGPUB	2004/09/30
476	BRS	14	(((gate or electrode) with (counter$1dope or counter$1doping or counter$1dopant or (counter adj (dope or doping or dopant	USPAT: US-PGPUB	2004/09/30
477	BRS	14	((gate or electrode) with (counter$1dope or counter$1doping or counter$1dopant or (counter adj (dope or doping or dopant	USPAT: US-PGPUB	2004/09/30
478	BRS	0	((gate or electrode) with ((anneal or annealing or annealed or activate or activating or activated or annealing) adj "both" adj	USPAT: US-PGPUB	2004/09/30
479	BRS	0	((gate or electrode) with ((anneal or annealing or annealed or activate or activating or activated or annealing) adj "both" adj	USPAT: US-PGPUB	2004/09/30
480	BRS	1	((((anneal or annealing or annealed or activate or activating or activated or annealing) adj "both" adj (impurity or conductivity)	USPAT: US-PGPUB	2004/09/30